

Aerospace 1 x 15 A and 2 x 15 A - 200 V fast recovery rectifier

Features

- Very small conduction losses
- Negligible switching losses
- High surge current capability
- High avalanche energy capability
- Hermetic packages
- Target radiation qualification:
 - 150 krad (Si) low dose rate
 - 1 Mrad high dose rate
- ESCC qualified

Description

Packaged in hermetic TO-254 or SMD.5, this device is intended for use in medium voltage, high frequency switching mode power supplies, high frequency DC to DC converters, and other aerospace applications.

The complete ESCC specification for this device is available from the European Space Agency web site. ST guarantees full compliance of qualified parts with such ESCC detailed specifications.



Figure 1. Device configurations

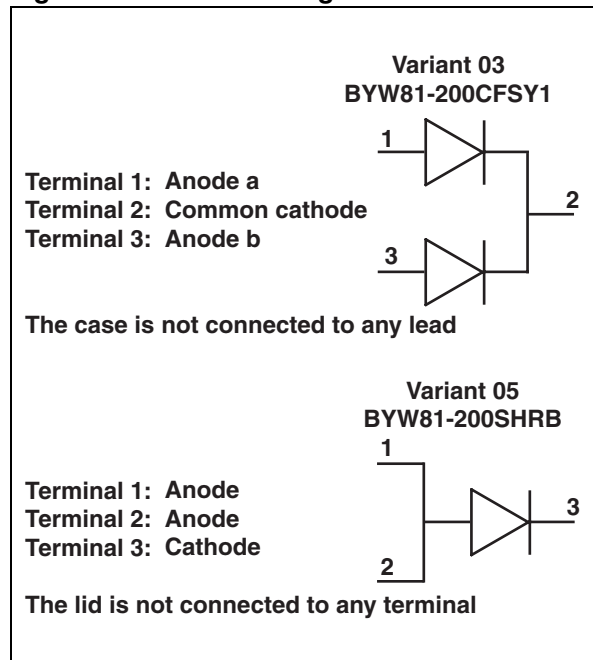


Table 1. Device summary⁽¹⁾

Order code	ESCC part number	Quality level	EPPL	Package	$I_{F(AV)}$	V_{RRM}	$V_F (max)$	$T_{j(max)}$
BYW81-200CFSY1	-	Engineering model	-	TO-254	2 x 15 A	200 V	1.15 V	150 °C
BYW81-200CFSYHRB	5103/029/03	ESCC flight	-	TO-254	2 x 15 A			
BYW81-200SHRB	5103/029/05	ESCC flight	Y	SMD.5	15 A			

1. Contact ST sales office for information about the specific conditions for products in die form and QML-Q versions.

1 Characteristics

Table 2. Absolute maximum ratings

Symbol	Characteristic	Value	Unit
I_{FSM}	Forward surge current ⁽¹⁾ ⁽²⁾		
	Variant 05	250	A
	Variant 03 (per diode)	250	
	Variant 03 (per device)	500	
V_{RRM}	Repetitive peak reverse voltage ⁽³⁾	200	V
I_O	Average output rectified current (50% duty cycle) ⁽²⁾ ⁽⁴⁾		
	Variant 05	15	A
	Variant 03 (per diode)	15	
	Variant 03 (per device)	30	
$I_{F(RMS)}$	Forward rms current (per diode) ⁽²⁾		
	Variant 05	30	A
	Variant 03 (per diode)	30	
	Variant 03 (per device)	40	
T_{OP}	Operating case temperature range ⁽⁵⁾	-55 to +150	°C
T_J	Junction temperature	+150	°C
T_{STG}	Storage temperature range ⁽⁵⁾	-55 to +150	°C
T_{SOL}	Soldering temperature		
	TO-254 ⁽⁶⁾	+260	°C
	SMD.5 ⁽⁷⁾	+245	

1. Sinusoidal pulse of 10 ms duration
2. For variant 03 the "per device" ratings apply only when both cathode terminals are tied together.
3. Pulsed, duration 5 ms, F = 50 Hz
4. For $T_{case} \geq +110^{\circ}\text{C}$, derate linearly to 0 A at $+150^{\circ}\text{C}$.
5. For devices with hot solder dip lead finish all testing performed at $T_{amb} > +125^{\circ}\text{C}$ are carried out in a 100% inert atmosphere.
6. Duration 10 seconds maximum at a distance of not less than 1.5 mm from the device body and the same lead shall not be resoldered until 3 minutes have elapsed.
7. Duration 5 seconds maximum the same package shall not be resoldered until 3 minutes have elapsed.

Table 3. Thermal resistance

Symbol	Parameter	Value	Unit
$R_{th(j-c)}^{(1)}$	Junction to case		
	All variants (per diode)	2.3	°C/W
	Variant 03 (per device) ⁽²⁾	1.4	

1. Package mounted on infinite heatsink.
2. For variant 03 the "per device" ratings apply only when both cathode terminals are tied together.

Table 4. Electrical measurements at ambient temperature (per diode), $T_{amb} = 22 \pm 3 \text{ }^{\circ}\text{C}$

Symbol	Characteristic	MIL-STD-750 test method	Test conditions	Limits		Units
				Min.	Max.	
I_R	Reverse current	4016	DC method, $V_R = 200 \text{ V}$	-	20	μA
$V_{F1}^{(1)}$	Forward voltage	4011	Pulse method, $I_F = 10 \text{ A}$	-	1.0	V
$V_{F2}^{(1)}$			Pulse method, $I_F = 20 \text{ A}$	-	1.2	V
V_{BR}	Breakdown voltage	4021	$I_R = 100 \mu\text{A}$	200	-	V
C	Capacitance	4001	$V_R = 10 \text{ V}$, $F = 1 \text{ MHz}$	-	220	pF
t_{rr}	Reverse recovery time	4031	$I_F = 1 \text{ A}$, $V_R = 30 \text{ V}$, $di_F/dt = -50 \text{ A}/\mu\text{s}$	-	40	ns
$Z_{th(j-c)}^{(2)}$	Relative thermal impedance, junction to case	3101	$I_H = 15 \text{ to } 40 \text{ A}$, $t_H = 50 \text{ ms}$ $I_M = 50 \text{ mA}$, $t_{md} = 100 \mu\text{s}$	Calculate $\Delta V_F^{(3)}$		$^{\circ}\text{C}/\text{W}$

1. Pulse width $\leq 300 \mu\text{s}$, duty cycle $\leq 2\%$
2. Performed only during screening tests parameter drift values (initial measurements), go-no-go.
3. The limits for ΔV_F shall be defined by the manufacturer on every lot in accordance with MIL-STD-750 Method 3101 and shall guarantee the $R_{th(j-c)}$ limits specified in maximum ratings.

Table 5. Electrical measurements at high and low temperatures (per diode)

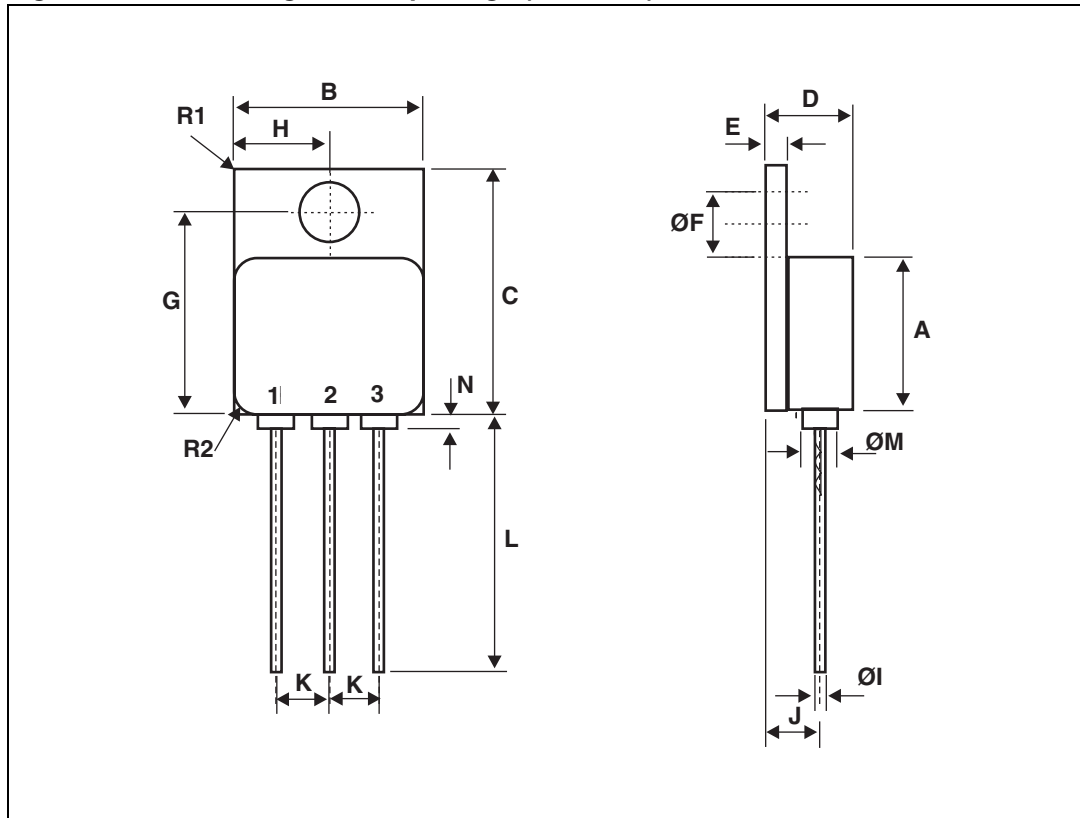
Symbol	Characteristic	MIL-STD-750 test method	Test conditions ⁽¹⁾	Limits		Units
				Min.	Max.	
I_R	Reverse current	4016	$T_{case} = +125 (+0, -5) ^{\circ}\text{C}$ DC method, $V_R = 200 \text{ V}$	-	10	mA
$V_{F1}^{(2)}$	Forward voltage	4011	$T_{case} = +125 (+0, -5) ^{\circ}\text{C}$ pulse method, $I_F = 10 \text{ A}$	-	0.85	V
			$T_{case} = +55 (+0, -5) ^{\circ}\text{C}$ pulse method, $I_F = 10 \text{ A}$	-	1.15	V

1. Read and record measurements shall be performed on a sample of 5 components with 0 failures allowed. Alternatively a 100% inspection may be performed.
2. Pulse width $\leq 300 \mu\text{s}$, duty cycle $\leq 2\%$

2 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK[®] packages, depending on their level of environmental compliance. ECOPACK[®] specifications, grade definitions and product status are available at: www.st.com. ECOPACK[®] is an ST trademark.

Figure 2. Metal flange mount package (TO-254^(a)) 3 lead, dimension definitions

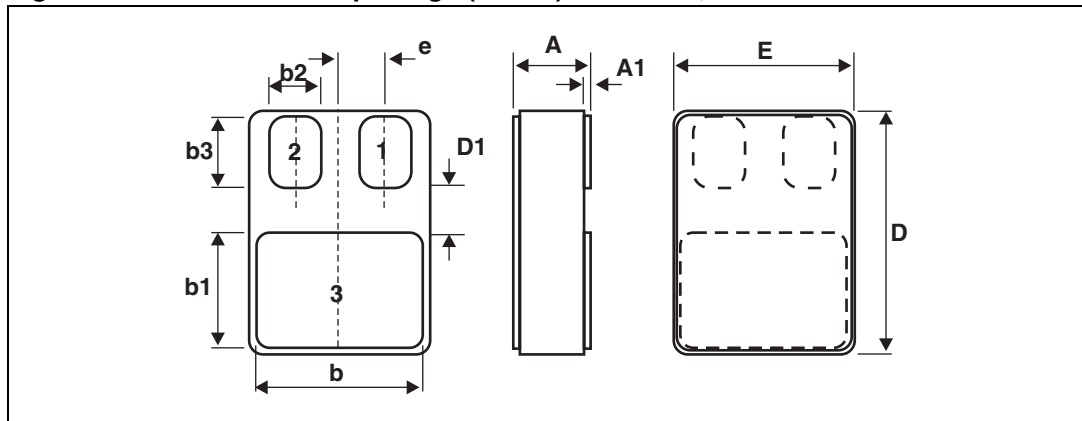


a. The terminal identification is specified by the device configuration. See [Figure 1](#) for terminal connections

Table 6. Metal flange mount package (TO-254) 3-lead, dimension values

Reference	Dimension in millimetres		Dimlension in inches	
	Min.	Max.	Min.	Max.
A	13.59	13.84	0.535	0.545
B	13.59	13.84	0.535	0.545
C	20.07	20.32	0.790	0.800
D	6.3	6.7	0.248	0.264
E	1	3.9	0.039	0.154
ØF	3.5	3.9	0.138	0.154
G	16.89	17.4	0.665	0.685
H	6.86 BSC		0.270 BSC	
ØI ⁽¹⁾	0.89	1.14	0.035	0.045
J	3.81 BSC		0.150 BSC	
K	3.81 BSC		0.150 BSC	
L	12.95	14.5	0.510	0.571
ØM	3.05 Typ.		0.120 Typ.	
N	-	0.71	-	0.028
R1 ⁽²⁾	-	1	-	0.039
R2 ⁽³⁾	1.65 Typ.		0.065	

1. 3 locations
2. Radius of heatsink flange corner - 4 locations
3. Radius of body corner - 4 locations

Figure 3. Surface mount package (SMD.5) 3-terminal, dimension definitions**Table 7. Surface mount package (SMD.5) 3-terminal, dimension values**

Reference	Dimension in millimetres		Dimension in inches	
	Min.	Max.	Min.	Max.
A	2.84	3.15	0.112	0.124
A1	0.25	0.51	0.010	0.20
b	7.13	7.39	0.281	0.291
b1	5.58	5.84	0.220	0.230
b2 ⁽¹⁾	2.28	2.54	0.090	0.100
b3 ⁽¹⁾	2.92	3.18	0.115	0.125
D	10.03	10.28	0.395	0.405
D1 ⁽¹⁾	0.76	-	0.030	-
E	7.39	7.64	0.291	0.301
e ⁽¹⁾	1.91 BSC		0.075	

1. 2 locations

3 Ordering information

Table 8. Ordering information⁽¹⁾

Order code	ESCC part number	Quality level	EPPL	Package	Lead finish	Marking	Mass	Packing
BYW81-200CFSY1	-	Engineering model	-	TO-254	Gold	BYW81200CFSY1 + BeO	10 g	Strip pack
BYW81-200FSYHRB	5103/029/03	ESCC flight	-	TO-254	Solder dip	510302901 + BeO		
BYW81-200SHRB	5103/029/05	ESCC flight	Y	SMD.5	Gold	510302905	2.0 g	

1. Contact ST sales office for information about the specific conditions for products in die form and QML-Q versions.

4 Revision history

Table 9. Document revision history

Date	Revision	Changes
03-Nov-2010	1	First issue.

Please Read Carefully:

Information in this document is provided solely in connection with ST products. STMicroelectronics NV and its subsidiaries ("ST") reserve the right to make changes, corrections, modifications or improvements, to this document, and the products and services described herein at any time, without notice.

All ST products are sold pursuant to ST's terms and conditions of sale.

Purchasers are solely responsible for the choice, selection and use of the ST products and services described herein, and ST assumes no liability whatsoever relating to the choice, selection or use of the ST products and services described herein.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted under this document. If any part of this document refers to any third party products or services it shall not be deemed a license grant by ST for the use of such third party products or services, or any intellectual property contained therein or considered as a warranty covering the use in any manner whatsoever of such third party products or services or any intellectual property contained therein.

UNLESS OTHERWISE SET FORTH IN ST'S TERMS AND CONDITIONS OF SALE ST DISCLAIMS ANY EXPRESS OR IMPLIED WARRANTY WITH RESPECT TO THE USE AND/OR SALE OF ST PRODUCTS INCLUDING WITHOUT LIMITATION IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION), OR INFRINGEMENT OF ANY PATENT, COPYRIGHT OR OTHER INTELLECTUAL PROPERTY RIGHT.

UNLESS EXPRESSLY APPROVED IN WRITING BY AN AUTHORIZED ST REPRESENTATIVE, ST PRODUCTS ARE NOT RECOMMENDED, AUTHORIZED OR WARRANTED FOR USE IN MILITARY, AIR CRAFT, SPACE, LIFE SAVING, OR LIFE SUSTAINING APPLICATIONS, NOR IN PRODUCTS OR SYSTEMS WHERE FAILURE OR MALFUNCTION MAY RESULT IN PERSONAL INJURY, DEATH, OR SEVERE PROPERTY OR ENVIRONMENTAL DAMAGE. ST PRODUCTS WHICH ARE NOT SPECIFIED AS "AUTOMOTIVE GRADE" MAY ONLY BE USED IN AUTOMOTIVE APPLICATIONS AT USER'S OWN RISK.

Resale of ST products with provisions different from the statements and/or technical features set forth in this document shall immediately void any warranty granted by ST for the ST product or service described herein and shall not create or extend in any manner whatsoever, any liability of ST.

ST and the ST logo are trademarks or registered trademarks of ST in various countries.

Information in this document supersedes and replaces all information previously supplied.

The ST logo is a registered trademark of STMicroelectronics. All other names are the property of their respective owners.

© 2010 STMicroelectronics - All rights reserved

STMicroelectronics group of companies

Australia - Belgium - Brazil - Canada - China - Czech Republic - Finland - France - Germany - Hong Kong - India - Israel - Italy - Japan - Malaysia - Malta - Morocco - Philippines - Singapore - Spain - Sweden - Switzerland - United Kingdom - United States of America

www.st.com